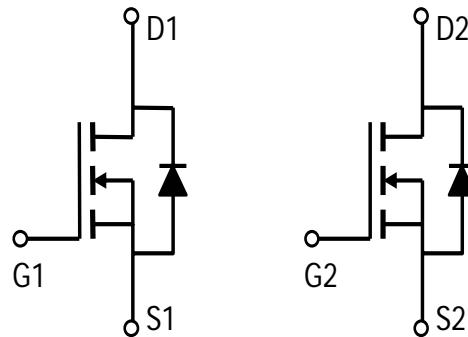


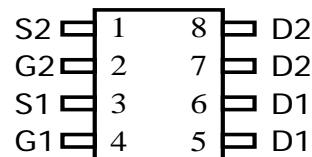
## Description

The AO4828 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.



## General Features

$V_{DS} = 60V$   $I_D = 6.5A$   
 $R_{DS(ON)} < 36m\Omega$  @  $V_{GS}=10V$   
 $R_{DS(ON)} < 47m\Omega$  @  $V_{GS}=4.5V$



## Application

Battery protection  
Load switch  
Uninterruptible power supply

## Absolute Maximum Ratings@ $T_j=25^\circ C$ (unless otherwise specified)

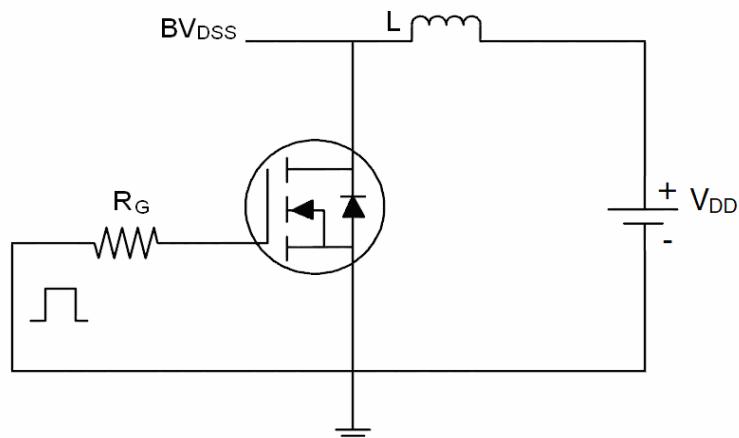
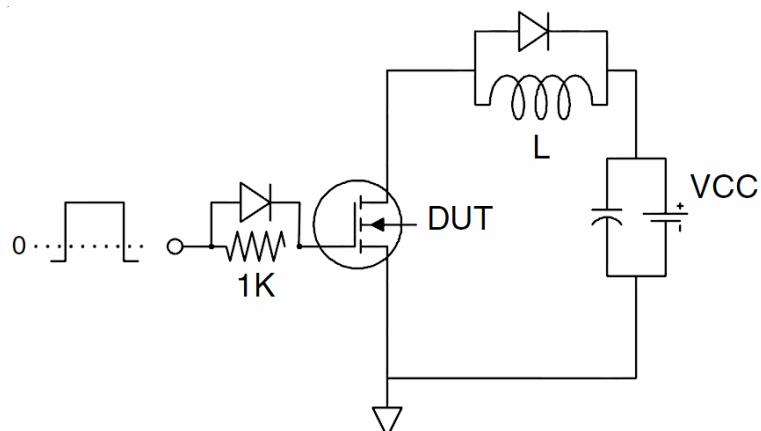
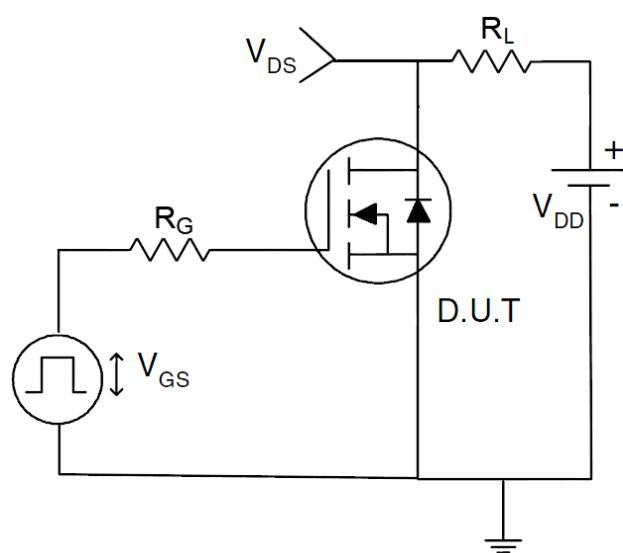
Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	60	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D@T_A=25^\circ C$	Drain Current, $V_{GS}$ @ $4.5V^3$	6.5	A
$I_D@T_A=70^\circ C$	Drain Current, $V_{GS}$ @ $4.5V^3$	5	A
$I_{DM}$	Pulsed Drain Current <sup>1</sup>	30	A
$P_D@T_A=25^\circ C$	Total Power Dissipation	2.1	W
$T_{STG}$	Storage Temperature Range	-55 to 150	$^\circ C$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^\circ C$
$R_{thj-a}$	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	60	$^\circ C/W$

**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)**

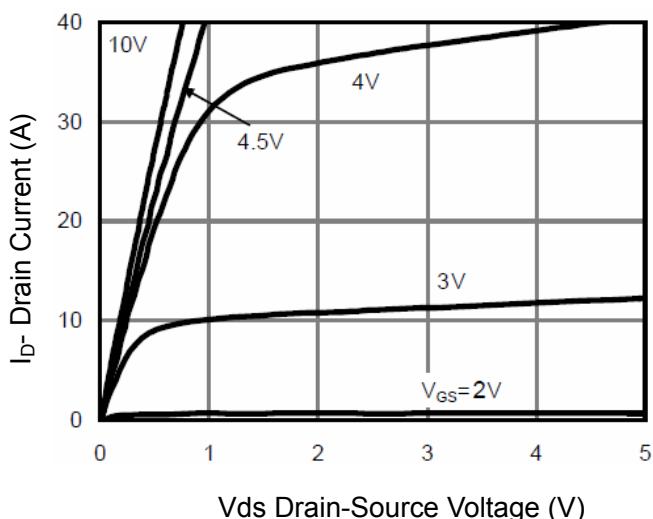
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	60	69	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=60\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm100$	nA
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	1.0	1.5	2.5	V
Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=6\text{A}$		30	36	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=4\text{A}$		36	47	$\text{m}\Omega$
Forward Transconductance	$g_{\text{FS}}$	$V_{\text{DS}}=5\text{V}, I_{\text{D}}=6\text{A}$		20	-	S
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=25\text{V}, V_{\text{GS}}=0\text{V}, F=1.0\text{MHz}$		1920		PF
Output Capacitance	$C_{\text{oss}}$			155		PF
Reverse Transfer Capacitance	$C_{\text{rss}}$			116		PF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DS}}=30\text{V}, R_{\text{L}}=4.7\Omega$ $V_{\text{GS}}=10\text{V}, R_{\text{GEN}}=3\Omega$	-	8	-	nS
Turn-on Rise Time	$t_{\text{r}}$		-	5	-	nS
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	29	-	nS
Turn-Off Fall Time	$t_{\text{f}}$		-	6	-	nS
Total Gate Charge	$Q_{\text{g}}$	$V_{\text{DS}}=30\text{V}, I_{\text{D}}=6\text{A}, V_{\text{GS}}=10\text{V}$	-	50	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	8	-	nC
Gate-Drain Charge	$Q_{\text{gd}}$		-	16	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{s}}=6\text{A}$	-	-	1.2	V
Diode Forward Current <sup>(Note 2)</sup>	$I_{\text{s}}$		-	-	7	A
Reverse Recovery Time	$t_{\text{rr}}$	$T_{\text{J}} = 25^\circ\text{C}, I_{\text{F}} = 7\text{A}$ $dI/dt = 100\text{A}/\mu\text{s}$ <sup>(Note 3)</sup>	-	35	-	nS
Reverse Recovery Charge	$Q_{\text{rr}}$		-	43	-	nC
Forward Turn-On Time	$t_{\text{on}}$	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

**Notes:**

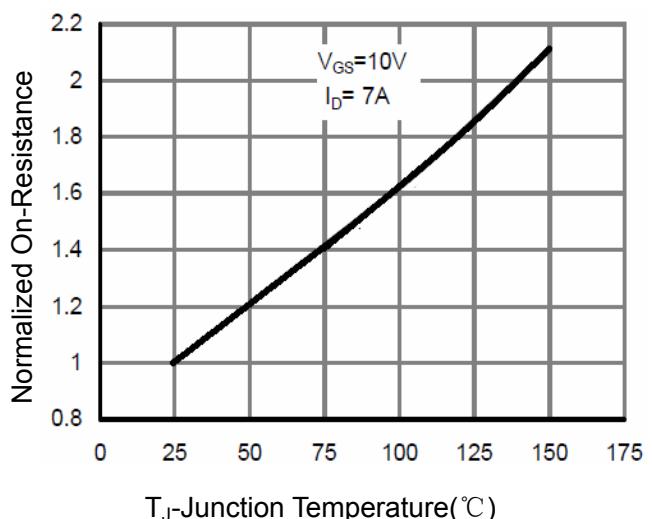
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

**Test Circuit****1) E<sub>AS</sub> test Circuits****2) Gate charge test Circuit****3) Switch Time Test Circuit**

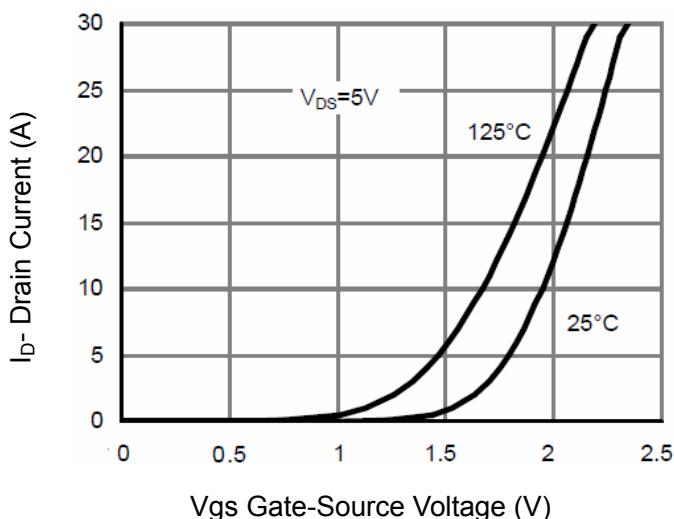
**Typical Electrical and Thermal Characteristics (Curves)**



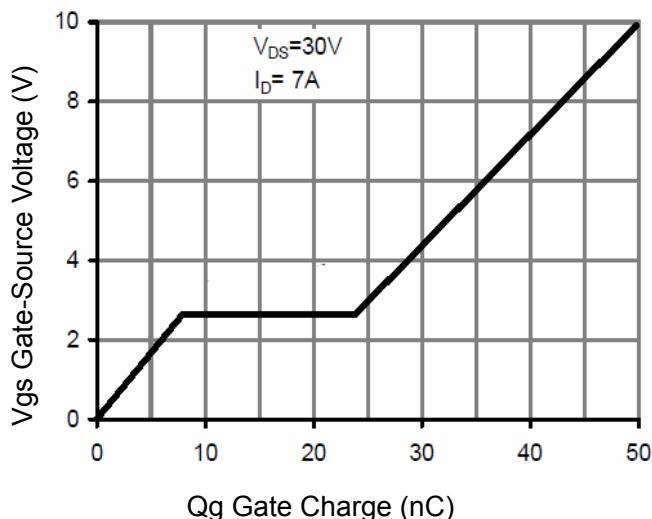
**Figure 1 Output Characteristics**



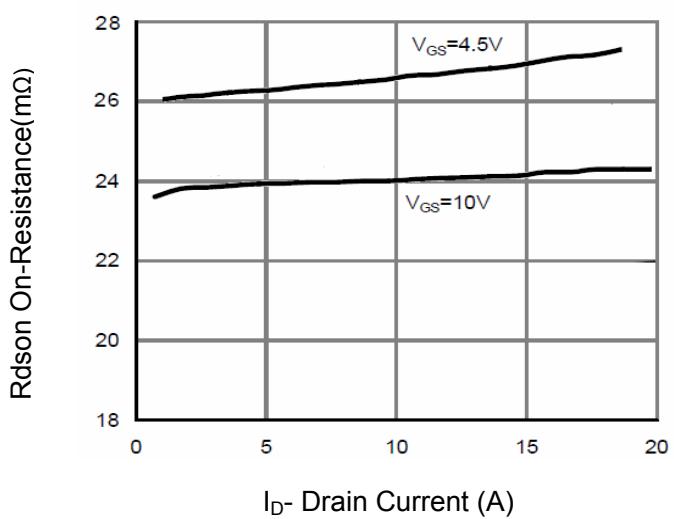
**Figure 4  $R_{DSON}$ -Junction Temperature**



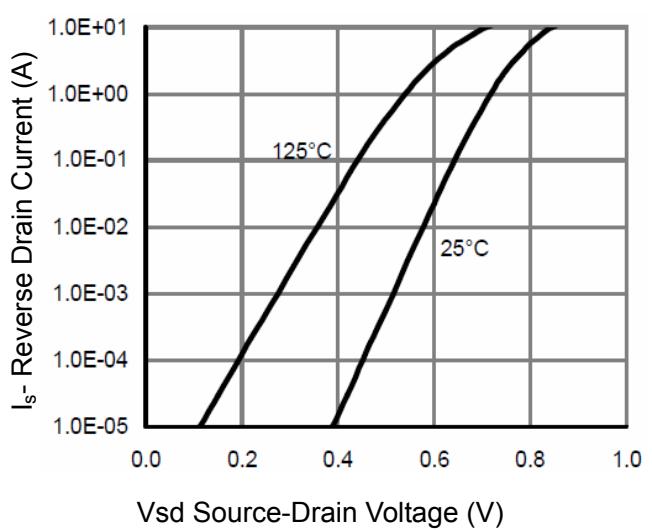
**Figure 2 Transfer Characteristics**



**Figure 5 Gate Charge**



**Figure 3  $R_{DSON}$ - Drain Current**



**Figure 6 Source-Drain Diode Forward**

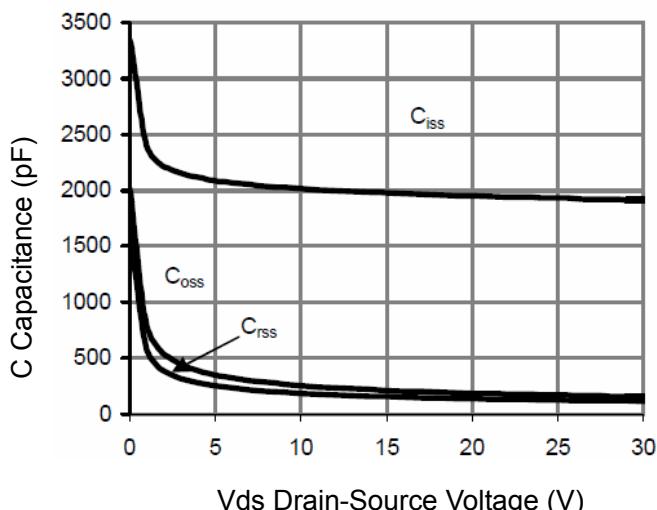


Figure 7 Capacitance vs Vds

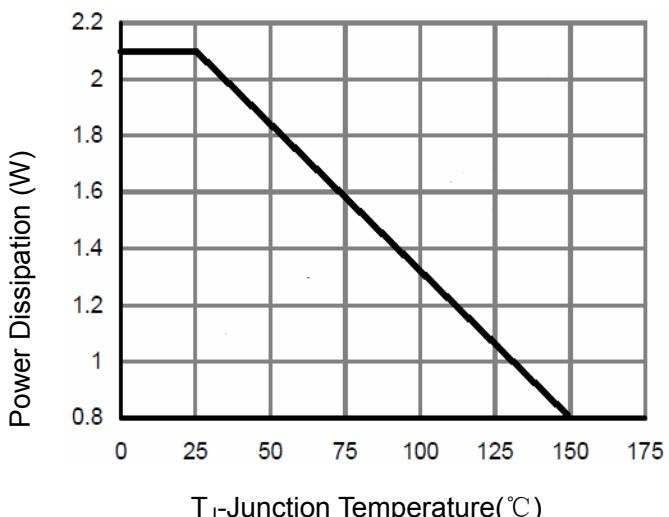


Figure 9 Power De-rating

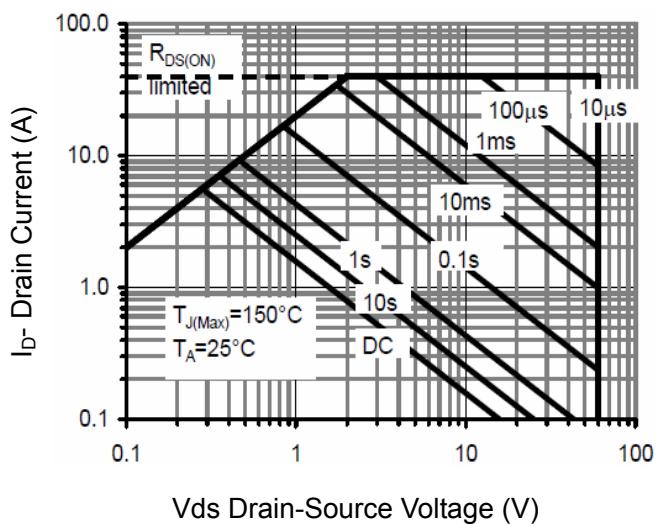


Figure 8 Safe Operation Area

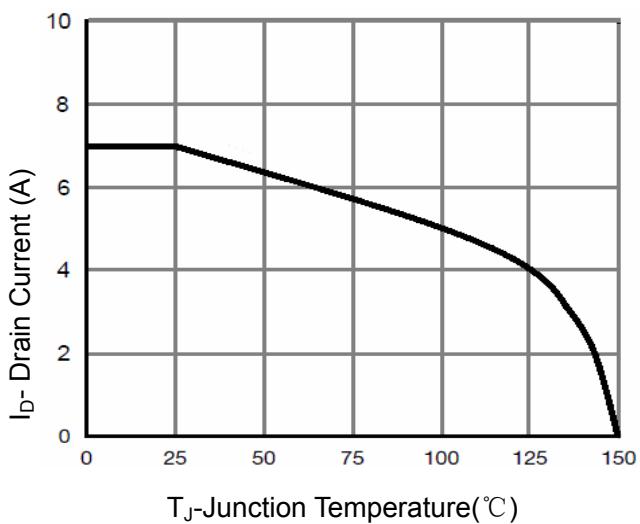


Figure 10 Current De-rating

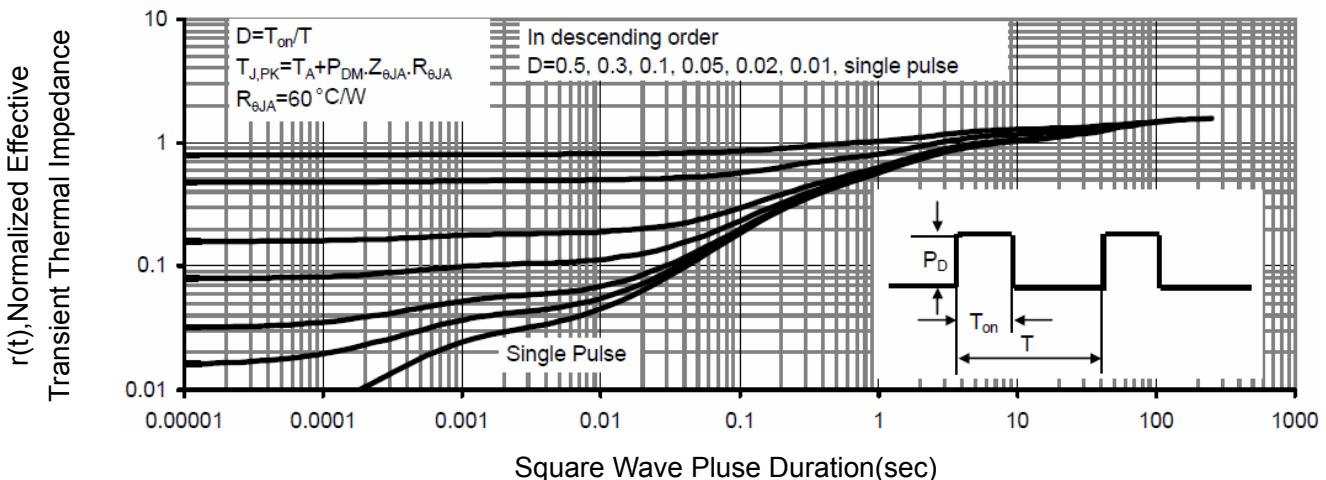
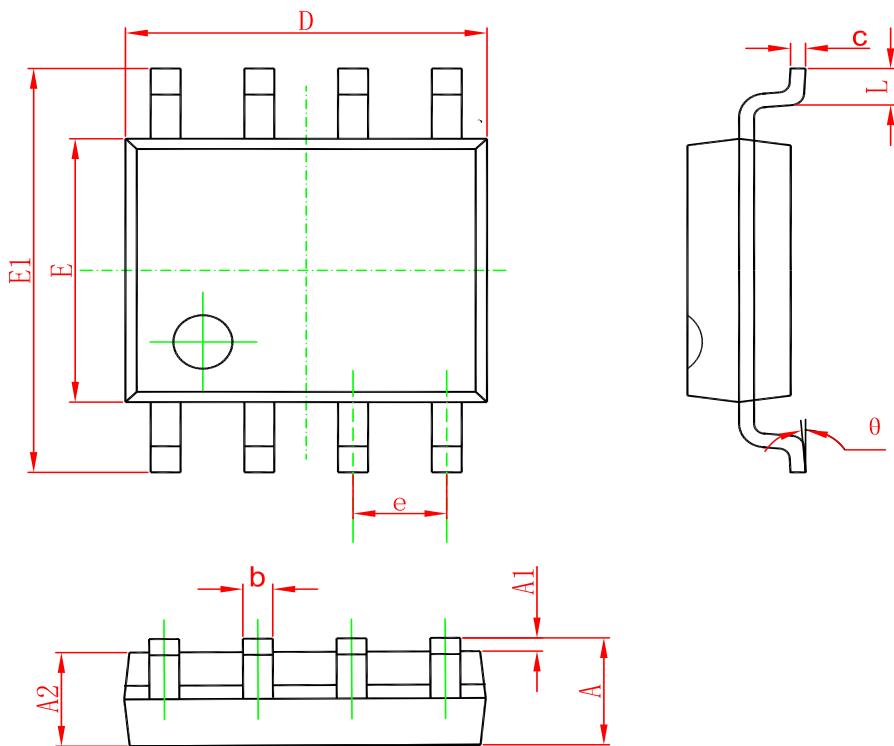


Figure 11 Normalized Maximum Transient Thermal Impedance

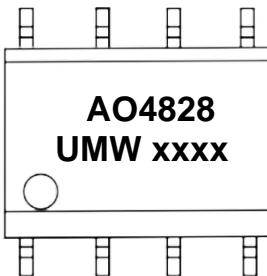
## PACKAGE OUTLINE DIMENSIONS

SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

## Marking



("xxxx"代表年份周期)

## Ordering information

Order code	Package	Baseqty	Deliverymode
UMW AO4828	SOP-8	3000	Tape and reel